

# isc N-Channel MOSFET Transistor

## AOTF240L

#### FEATURES

- Drain Current –I\_D= 85A@ T\_C=25 $^\circ\!\mathrm{C}$
- Drain Source Voltage-: V<sub>DSS</sub>= 40V(Min)
- Static Drain-Source On-Resistance
- :  $R_{DS(on)}$  = 2.9m  $\Omega$  (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRIPTION

• Designed for use in switch mode power supplies and general purpose applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25 C)					
SYMBOL	PARAMETER	VALUE	UNIT		
V <sub>DSS</sub>	Drain-Source Voltage	40	V		
$V_{GS}$	Gate-Source Voltage-Continuous	±20	V		
ID	Drain Current-Continuous	85	А		
I <sub>DM</sub>	Drain Current-Single Pluse	400	А		
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25℃	41	W		
TJ	Max. Operating Junction Temperature	-55~175	°C		
T <sub>stg</sub>	Storage Temperature	-55~175	°C		

## ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

# pin 1.Gate 2.Drain 3.Source TO-220F package

F

B	10.00	10.10
C	4.40	4.60
D	0.75	0.90
F	3.10	3.30
Н	3.70	3.90
J	0.50	0.70
K	13.4	13.6
L	1.10	1.30
N	5.00	5.20
Q	2.70	2.90
R	2.20	2.40
S	2.65	2.90
U	6.40	6.60

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	3.6	°C/W

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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	40		V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> = 0.25mA	1	2.2	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 20A V <sub>GS</sub> = 10V; I <sub>D</sub> = 20A;T <sub>J</sub> =125°C		2.9 4.7	mΩ
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0		±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 40V; V <sub>GS</sub> = 0 V <sub>DS</sub> = 40V; V <sub>GS</sub> = 0;T <sub>J</sub> =55°C		1 5	μA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 1A; V <sub>GS</sub> = 0		1	V

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